

54F/74F189 64-Bit Random Access Memory with TRI-STATE® Outputs

General Description

The 'F189 is a high-speed 64-bit RAM organized as a 16-word by 4-bit array. Address inputs are buffered to minimize loading and are fully decoded on-chip. The outputs are TRI-STATE and are in the high impedance state whenever the Chip Select $(\overline{\text{CS}})$ input is HIGH. The outputs are active only in the Read mode and the output data is the complement of the stored data.

Features

- TRI-STATE outputs for data bus applications
- Buffered inputs minimize loading
- Address decoding on-chip
- Diode clamped inputs minimize ringing
- Available in SOIC, (300 mil only)

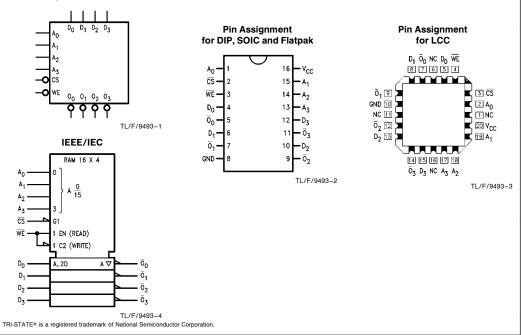
Commercial	Military	Package Number	Package Description		
74F189PC		N16E	16-Lead (0.300" Wide) Molded Dual-In-Line		
	54F189DL (Note 2)	J16A	16-Lead Ceramic Dual-In-Line		
74F189SC (Note 1)		M16A	16-Lead (0.150" Wide) Molded Small Outline, JEDEC		
74F189SJ (Note 1)		M16D	16-Lead (0.300" Wide) Molded Small Outline, EIAJ		
	54F189FL (Note 2)	W16A	16-Lead Cerpack		
	54F189LL (Note 2)	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C		

Note 1: Devices also available in 13" reel. Use suffix = SCX and SJX.

Note 2: Military grade device with environmental and burn-in processing. Use suffix = DLQB, FLQB and LLQB.

Logic Symbols

Connection Diagrams



Unit Loading/Fan Out

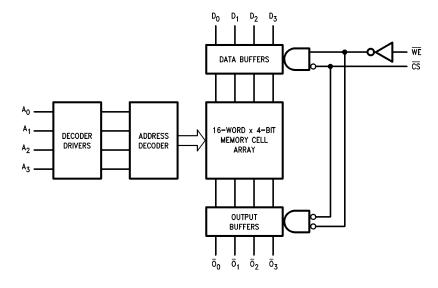
		54F/74F				
Pin Names	Description	U.L. HIGH/LOW	Input I _{IH} /I _{IL} Output I _{OH} /I _{OL}			
A ₀ -A ₃	Address Inputs	1.0/1.0	20 μA/-0.6 mA			
A ₀ -A ₃ CS	Chip Select Input (Active LOW)	1.0/1.0	20 μA/ – 1.2 mA			
WE	Write Enable Input (Active LOW)	1.0/1.0	$20 \mu\text{A}/-0.6 \text{mA}$			
D ₀ -D ₃	Data Inputs	1.0/1.0	20 μA/ – 0.6 mA			
$\overline{O}_0 - \overline{O}_3$	Inverted Data Outputs	150/40 (33.3)	-3.0 mA/24 mA (20 mA)			

Function Table

	Inputs CS WE		Operation	Condition of Outputs				
			Орогалон					
	L	L	Write	High Impedance				
	L	Н	Read	Complement of Stored Data				
	Н	Χ	Inhibit	High Impedance				

$$\begin{split} \mathsf{H} &= \mathsf{HIGH} \; \mathsf{Voltage} \; \mathsf{Level} \\ \mathsf{L} &= \mathsf{LOW} \; \mathsf{Voltage} \; \mathsf{Level} \\ \mathsf{X} &= \mathsf{Immaterial} \end{split}$$

Block Diagram



TL/F/9493-5

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

 $\begin{array}{lll} \text{Storage Temperature} & -65^{\circ}\text{C to} + 150^{\circ}\text{C} \\ \text{Ambient Temperature under Bias} & -55^{\circ}\text{C to} + 125^{\circ}\text{C} \\ \text{Junction Temperature under Bias} & -55^{\circ}\text{C to} + 175^{\circ}\text{C} \\ \text{Plastic} & -55^{\circ}\text{C to} + 150^{\circ}\text{C} \\ \end{array}$

V_{CC} Pin Potential to

 Ground Pin
 -0.5V to +7.0V

 Input Voltage (Note 2)
 -0.5V to +7.0V

 Input Current (Note 2)
 -30 mA to +5.0 mA

Voltage Applied to Output in HIGH State (with $V_{CC} = 0V$)

 $\begin{array}{lll} \text{Standard Output} & -0.5 \text{V to V}_{\text{CC}} \\ \text{TRI-STATE Output} & -0.5 \text{V to } +5.5 \text{V} \end{array}$

Current Applied to Output

in LOW State (Max) twice the rated I_{OL} (mA)

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature

Supply Voltage

Military + 4.5V to + 5.5V Commercial + 4.5V to + 5.5V

DC Electrical Characteristics

Symbol	Symbol Parameter		54F/74F			Units	V _{CC}	Conditions	
Syllibol			Min	Тур	Max	Units	V CC	Conditions	
V _{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal	
V _{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal	
V_{CD}	Input Clamp Diode Vo	oltage			-1.2	V	Min	$I_{IN} = -18 \text{ mA}$	
V _{OH}	Output HIGH Voltage	54F 10% V _{CC} 54F 10% V _{CC} 74F 10% V _{CC} 74F 10% V _{CC} 74F 5% V _{CC} 74F 5% V _{CC}	2.5 2.4 2.5 2.4 2.7 2.7			V	Min	$\begin{split} I_{OH} &= -1 \text{ mA} \\ I_{OH} &= -3 \text{ mA} \\ I_{OH} &= -1 \text{ mA} \\ I_{OH} &= -3 \text{ mA} \\ I_{OH} &= -1 \text{ mA} \\ I_{OH} &= -3 \text{ mA} \\ \end{split}$	
V _{OL}	Output LOW Voltage	54F 10% V _{CC} 74F 10% V _{CC}			0.5 0.5	V	Min	$I_{OL} = 20 \text{ mA}$ $I_{OL} = 24 \text{ mA}$	
I _{IH}	Input HIGH Current	54F 74F			20.0 5.0	μΑ	Max	V _{IN} = 2.7V	
I _{BVI}	Input HIGH Current Breakdown Test	54F 74F			100 7.0	μΑ	Max	V _{IN} = 7.0V	
I _{CEX}	Output HIGH Leakage Current	54F 74F			250 50	μΑ	Max	$V_{OUT} = V_{CC}$	
V _{ID}	Input Leakage Test	74F	4.75			V	0.0	$I_{\text{ID}} = 1.9 \mu\text{A}$ All Other Pins Grounded	
I _{OD}	Output Leakage Circuit Current	74F			3.75	μΑ	0.0	V _{IOD} = 150 mV All Other Pins Grounded	
I _{IL}	Input LOW Current				−0.6 −1.2	mA	Max	$V_{IN} = 0.5V \text{ (except } \overline{CS}\text{)}$ $V_{IN} = 0.5V \text{ (}\overline{CS}\text{)}$	
lozh	Output Leakage Current				50	μΑ	Max	V _{OUT} = 2.7V	
I _{OZL}	Output Leakage Current				-50	μΑ	Max	V _{OUT} = 0.5V	
I _{OS}	Output Short-Circuit Current		-60		-150	mA	Max	V _{OUT} = 0V	
I _{ZZ}	Bus Drainage Test				500	μΑ	0.0V	V _{OUT} = 5.25V	
I _{CCZ}	Power Supply Curren	t		37	55	mA	Max	V _O = HIGH Z	

AC Electrical Characteristics

Symbol	Parameter	$74F$ $T_{A} = +25^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50 \text{ pF}$			*T _A , V _{CC} = Mil C _L = 50 pF		74F T _A , V _{CC} = Com C _L = 50 pF		Units
		Min	Тур	Max	Min	Max	Min	Max	
t _{PLH} t _{PHL}	Access Time, HIGH or LOW A_n to \overline{O}_n	10.0 8.0	18.5 13.5	26.0 19.0	9.0 8.0	32.0 23.0	10.0 8.0	27.0 20.0	ns
t _{PZH}	Access Time, HIGH or LOW $\overline{\text{CS}}$ to $\overline{\text{O}}_{\text{n}}$	3.5 5.0	6.0 9.0	8.5 13.0	3.5 5.0	10.5 15.0	3.5 5.0	9.5 14.0	ns
t _{PHZ}	Disable Time, HIGH or LOW $\overline{\text{CS}}$ to $\overline{\text{O}}_{\text{n}}$	2.0 3.0	4.0 5.5	6.0 8.0	2.0 2.5	8.0 10.0	2.0 3.0	7.0 9.0	ns
t _{PZH}	Write Recovery Time, HIGH or LOW WE to O _n	6.5 6.5	15.0 11.0	28.0 15.5	6.5 6.5	37.5 17.5	6.5 6.5	29.0 16.5	ns
t _{PHZ}	Disable Time, HIGH or LOW $\overline{\text{WE}}$ to $\overline{\text{O}}_{\text{n}}$	4.0 5.0	7.0 9.0	10.0 13.0	3.5 5.0	12.0 15.0	4.0 5.0	11.0 14.0	ns

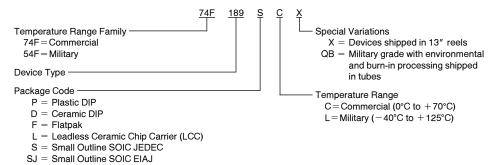
AC Operating Requirements

		$74F$ $T_A = +25^{\circ}C$ $V_{CC} = +5.0V$		54	F	74F T _A , V _{CC} = Com		Units
Symbol	Parameter			*T _A , V _C	_C = Mil			
		Min	Max	Min	Max	Min	Max	
t _s (H) t _s (L)	Setup Time, HIGH or LOW A _n to WE	0		0		0 0		
t _h (H)	Hold Time, HIGH or LOW A _n to WE	2.0 2.0		2.0 2.0		2.0 2.0		ns
t _s (H) t _s (L)	Setup Time, HIGH or LOW D _n to WE	10.0 10.0		11.0 11.0		10.0 10.0		
t _h (H) t _h (L)	Hold Time, HIGH or LOW D _n to WE	0		2.0 2.0		0 0		ns
t _S (L)	Setup Time, LOW CS to WE	0		0		0		
t _h (L)	Hold Time, LOW CS to WE	6.0		7.5		6.0		ns
t _w (L)	WE Pulse Width, LOW	6.0		15.0		6.0		ns

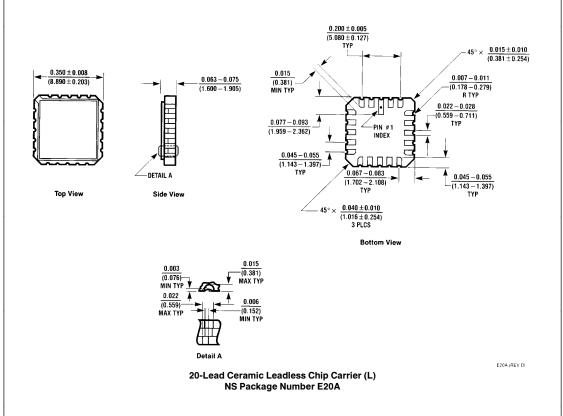
 $[*]T_A = -55^{\circ}C \text{ to } + 125^{\circ}C$

Ordering Information

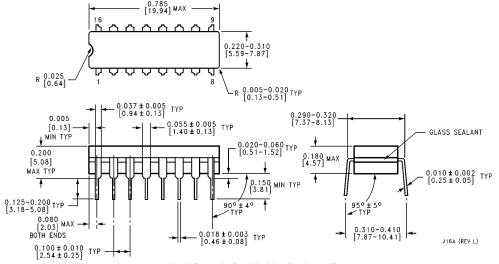
The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



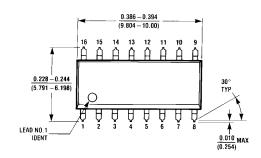
Physical Dimensions inches (millimeters)

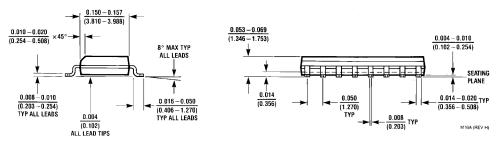




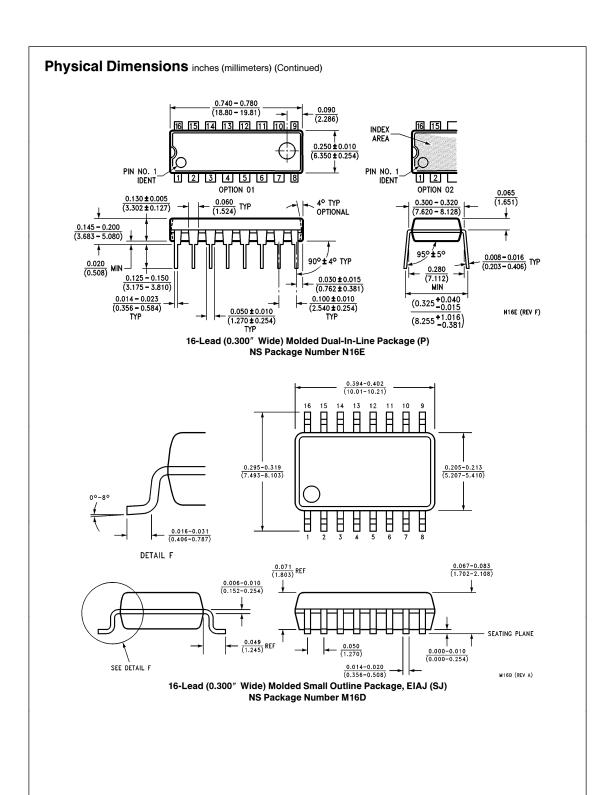


16-Lead Ceramic Dual-In-Line Package (D) NS Package Number J16A

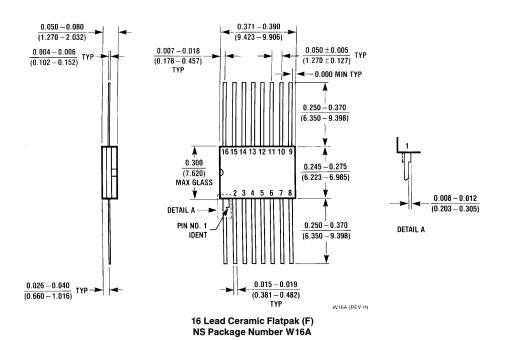




16-Lead (0.150" Wide) Molded Small Outline Package, JEDEC (S)
NS Package Number M16A



Physical Dimensions inches (millimeters) (Continued)



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